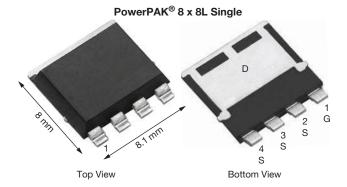
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Vishay Siliconix

Automotive N-Channel 80 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	80			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.003			
I _D (A)	150			
Configuration	Single			
Package	PowerPAK 8 x 8L			



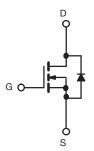
FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Fully lead (Pb)-free device
- Thin 1.9 mm height
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE



N-Channel MOSFET

ABSOLUTE MAXIMUM RATIN	GS ($T_C = 25$ °C, unles	s otherwise noted	i)	
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	80	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current	T _C = 25 °C	1	150	
Continuous Drain Current	T _C = 125 °C	- I _D	87	
Continuous Source Current (Diode conduc	Is	124	Α	
Pulsed Drain Current ^a		I _{DM}	210	
Single Pulse Avalanche Current		I _{AS}	53	
Single Pulse Avalanche Energy L = 0.1 mH		E _{AS}	140	mJ
Maximum Dower Dissipation	T _C = 25 °C	D	136	W
Maximum Power Dissipation	T _C = 125 °C	P_{D}	45	VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C
Soldering Recommendations (Peak temperature) c, d		-	260	C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB mount b	R _{thJA}	50	°C/W
Junction-to-Case (Drain)		R _{thJC}	1.1	C/VV

Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. When mounted on 1" square PCB (FR4 material).
- c. See solder profile (www.vishay.com/doc?73257). The PowerPAK 8 x 8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- d. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \mu A$		80	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	· V _{GS} , I _D = 250 μA	2.5	3	3.5	V	
Gate-Source Leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 80 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 80 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	-	-	50	μΑ	
		$V_{GS} = 0 V$	$V_{DS} = 80 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$	-	-	500		
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	50	-	1	Α	
		V _{GS} = 10 V	I _D = 20 A	-	0.0024	0.0030		
Drain-Source On-State Resistance a	R _{DS(on)}	V _{GS} = 10 V	$I_D = 20 \text{ A}, T_J = 125 ^{\circ}\text{C}$	-	-	0.0048	Ω	
		$V_{GS} = 10 \text{ V}$	$I_D = 20 \text{ A}, T_J = 175 ^{\circ}\text{C}$	-	-	0.0060		
Forward Transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 15 A		-	82	ı	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	6900	8625		
Output Capacitance	Coss	$V_{GS} = 0 V$ $V_{DS} = 25 V, f = 1 MHz$		-	3655	4570	рF	
Reverse Transfer Capacitance	C _{rss}			-	250	311		
Total Gate Charge c	Qg			-	82	144		
Gate-Source Charge c	Q _{gs}	$V_{GS} = 10 \text{ V}$	$V_{DS} = 40 \text{ V}, I_{D} = 10 \text{ A}$	-	11	-	nC	
Gate-Drain Charge ^c	Q_{gd}			-	21	-		
Gate Resistance	R _g		f = 1 MHz	0.4	0.8	1.2	Ω	
Turn-On Delay Time ^c	t _{d(on)}			-	19	30		
Rise Time ^c	t _r	$V_{DD} = 40 \text{ V, } R_L = 4 \Omega$ $I_D \cong 10 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 1 \Omega$		-	7.3	11	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	40	60		
Fall Time ^c	t _f			-	15	23		
Source-Drain Diode Ratings and Cha	racteristics b							
Pulsed Current ^a	I _{SM}			-	-	210	Α	
Forward Voltage	V_{SD}	I _F = 40 A, V _{GS} = 0 V		-	0.7	1.2	V	

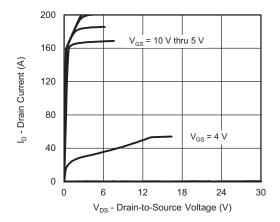
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

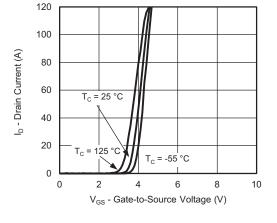
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



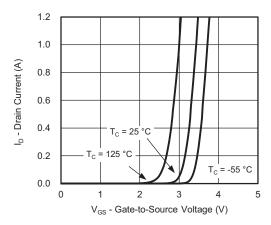
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



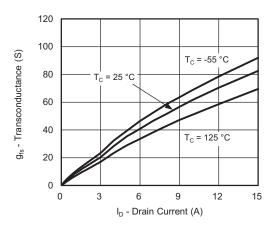
Output Characteristics



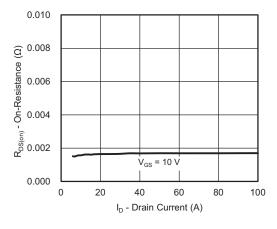
Transfer Characteristics



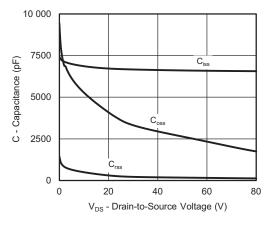
Transfer Characteristics



Transconductance



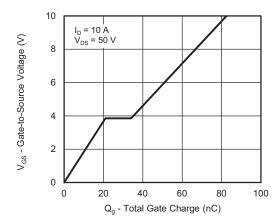
On-Resistance vs. Drain Current



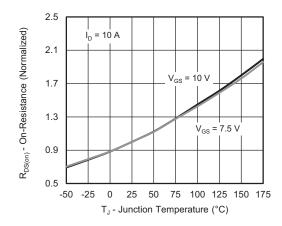
Capacitance



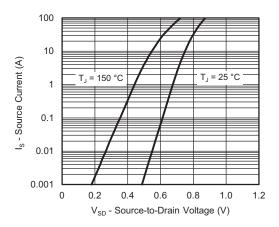
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



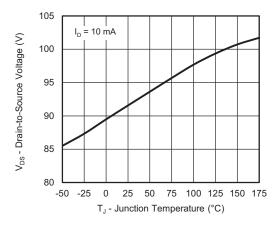
Gate Charge



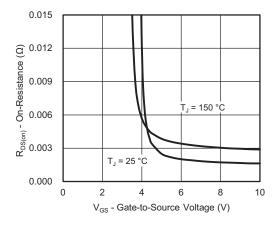
On-Resistance vs. Junction Temperature



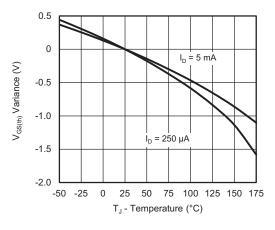
Source Drain Diode Forward Voltage



Drain Source Breakdown vs. Junction Temperature



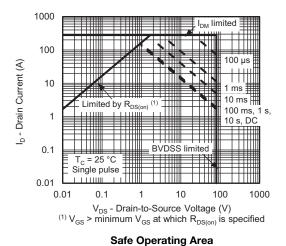
On-Resistance vs. Gate-to-Source Voltage



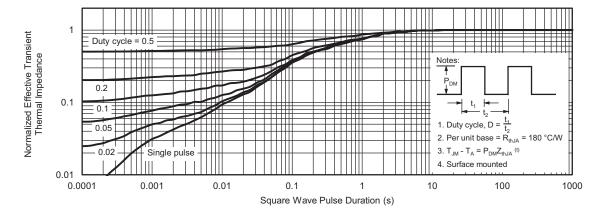
Threshold Voltage



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

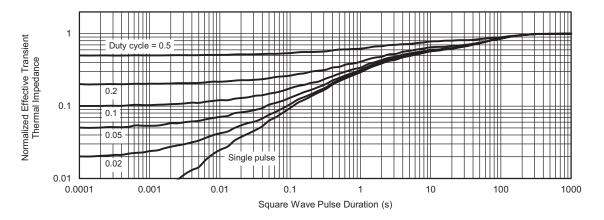


THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)

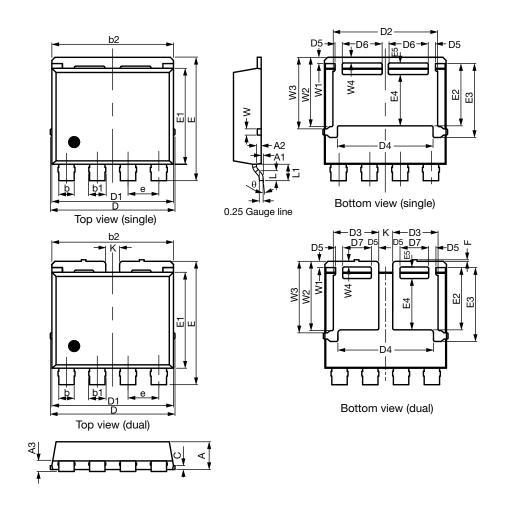


Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?76718.



PowerPAK® 8 x 8L Case Outline



DIM.	MILLIMETERS				INCHES	
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
Α	1.70	1.80	1.90	0.067	0.071	0.075
A1	0.00	0.08	0.13	0.000	0.003	0.005
A2	0.25	0.30	0.35	0.010	0.012	0.014
A3	0.55	0.62	0.70	0.022	0.024	0.028
b	0.92	1.00	1.08	0.036	0.039	0.043
b1	1.02	1.10	1.18	0.040	0.043	0.046
b2	7.80	7.90	8.00	0.307	0.311	0.315
С	0.20	0.25	0.30	0.008	0.010	0.012
D	8.00	8.10	8.25	0.315	0.319	0.325
D1	7.80	7.90	8.00	0.307	0.311	0.315
D2	6.70	6.80	6.90	0.264	0.268	0.272
D3	2.85	2.95	3.05	0.112	0.116	0.120
D4	6.11	6.21	6.31	0.241	0.244	0.248
D5	0.37	0.47	0.57	0.015	0.019	0.022
D6	2.49	2.59	2.69	0.098	0.102	0.106
D7	1.76	1.86	1.96	0.069	0.073	0.077

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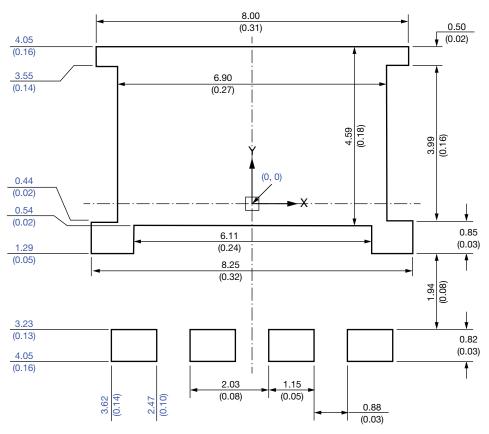
DIM.		MILLIMETERS		INCHES		
MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
е	1.95	2.00	2.05	0.077	0.079	0.081
E	7.90	8.00	8.10	0.311	0.315	0.319
E1	6.12	6.22	6.32	0.241	0.245	0.249
E2	3.94	4.04	4.14	0.140	0.159	0.163
E3	4.69	4.79	4.89	0.185	0.189	0.193
E4	3.23	3.33	3.43	0.127	0.131	0.135
E5	0.65	0.75	0.85	0.026	0.030	0.033
F	0.00	0.10	0.15	0.000	0.004	0.006
L	0.62	0.72	0.82	0.024	0.028	0.032
L1	0.92	1.07	1.22	0.036	0.042	0.048
K	0.80	0.90	1.00	0.031	0.035	0.039
W	0.30	0.40	0.50	0.012	0.016	0.020
W1	0.30	0.40	0.50	0.012	0.016	0.020
W2	4.39	4.49	4.59	0.173	0.177	0.181
W3	4.54	4.64	4.74	0.179	0.183	0.187
W4	0.32	0.37	0.42	0.013	0.015	0.017
θ	6°	10°	14°	6°	10°	14°

C17-1388-Rev. B, 16-Oct-17

DWG: 6026



Recommended Minimum PADs for PowerPAK® 8 x 8L Single



Dimensions in millimeters (inches)

Note

• Linear dimensions are in black, the same information is provided in ordinate dimensions which are in blue.



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